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U.S. Department of Commerce Patent and Trademark Office

Attorney's Docket No. 06816-035003

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Information Disclosure Statement
by Applicant

Applicant Sarath Gunapala et al.

Group Art Unit

2811

(Use several sheets if necessary)

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(AZ CFR \$1,98(b)) **U.S. Patent Documents** Desig. Examiner Patent Filing Date Initial ID Number Issue Date Patentee Class Subclass If Appropriate nm AA 5,488,504 Jan 30, 1996 Worchesky et al. AB AC AD ΑE

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation Yes No	
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Other Documents (include Author, Title, Date, and Place of Publication)			
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EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with					
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				Substitute Disclosure Form (PTO-1449)	